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IN THE CLAIMS:

1. (Currently Amended) A light-emitting device comprising:

a wiring formed on a first film;

a second film formed of the same layer as the wiring on the first film;

a third film formed over the first film; ~~and~~

a contact hole provided in the third film;

an electrode of a light-emitting element formed on the third film; and

a fourth film covering an edge of the electrode of the light-emitting element.

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the second film, ~~and~~

wherein the wiring is connected with the electrode of the light-emitting element in the contact hole.

wherein an opening of a the fourth film covering an edge of the electrode of the light-emitting element is provided in an overlap portion of the electrode of the light-emitting element and the second film, and

wherein a contact hole of the third film is overlapped with the fourth film.

2. (Original) The light-emitting device according to claim 1, wherein a reflective film is included in the electrode of the light-emitting element.

3. (Original) The light-emitting device according to claim 1 or claim 2, wherein the wiring is integrated with the second film.

4. (Original) The light-emitting device according to claim 1, wherein the second film has a film thickness equal to or thicker than that of the wiring.

5. (Currently Amended) A light-emitting device comprising:

a transistor including a semiconductor film, a gate insulating film, and a gate electrode;

a first film formed on the transistor;

a first contact hole provided in the first film;

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a wiring formed on the first film;
a second film formed of the same layer as the wiring on the first film;
a third film formed over the first film; and
a second contact hole provided in the third film;
an electrode of a light-emitting element formed on the third film[-]; and
a fourth film covering an edge of the electrode of the light-emitting element.

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the second film, and

wherein an opening of ~~a the fourth film covering an edge of the electrode of the light-emitting element~~ is provided in an overlap portion of the electrode of the light-emitting element and the second film, and

wherein a first contact hole of the first film and a second contact hole of the third film are overlapped with the fourth film.

6. (Original) The light-emitting device according to claim 5, wherein a reflective film is included in the electrode of the light-emitting element.

7. (Original) The light-emitting device according to claim 5 or claim 6, wherein the wiring is integrated with the second film.

8. (Original) The light-emitting device according to claim 5, wherein the second film has a film thickness equal to or thicker than that of the wiring.

9. (Currently Amended) A light-emitting device comprising:
a semiconductor film;
a gate insulating film formed on the semiconductor film;
a gate electrode formed on the gate insulating film;
a first film formed on the gate electrode;
a first contact hole provided in the first film;
a wiring formed on the first film;
a second film formed of the same layer as the wiring on the first film;

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a third film formed over the first film; and

a second contact hole provided in the third film;

an electrode of a light-emitting element formed on the third film^[,]; and

a fourth film covering an edge of the electrode of the light-emitting element.

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the second film, and

wherein an opening of ~~a the~~ fourth film ~~covering an edge of the electrode of the light-emitting element~~ is provided in an overlap portion of the electrode of the light-emitting element and the second film, and

wherein a first contact hole of the first film and a second contact hole of the third film are overlapped with the fourth film.

10. (Original) The light-emitting device according to claim 9, wherein a reflective film is provided in the electrode of the light-emitting element.

11. (Original) The light-emitting device according to claim 9 or claim 10, wherein the wiring is integrated with the second film.

12. (Original) The light-emitting device according to claim 9, wherein the second film has a film thickness equal to or thicker than that of the wiring.

13. (Currently Amended) A light-emitting device comprising:

a wiring conductive film formed on a first interlayer insulating film;

~~a conductive film formed of the same layer as the wiring on the first interlayer insulating film;~~

a second interlayer insulating film formed over the first interlayer insulating film; and

an electrode of a light-emitting element formed on the second interlayer insulating film;

a contact hole provided in the second interlayer insulating film; and

a partition layer covering an edge of the electrode of the light-emitting element.

wherein the electrode of the light-emitting element is electrically connected to the conductive film in the contact hole.

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wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the conductive film, and

wherein an opening of ~~a the partition layer covering an edge of the electrode of the light-emitting element~~ is provided in an overlap portion of the electrode of the light-emitting element and the conductive film, and

wherein the contact hole of the second interlayer insulating film is overlapped with the partition layer.

14. (Canceled)

15. (Canceled)

16. (Canceled)

17. (Canceled)

18. (New) A light-emitting device comprising:

a conductive film formed over a first insulating film;

a second insulating film formed over the first insulating film;

an electrode of a light-emitting element formed over the second insulating film;

a contact hole provided in the second insulating film; and

a partition layer covering an edge of the electrode of the light-emitting element,

wherein the electrode of the light-emitting element is electrically connected to the conductive film in the contact hole,

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the conductive film,

wherein an opening of the partition layer is provided in an overlap portion of the electrode of the light-emitting element and the conductive film, and

wherein the contact hole of the second insulating film is overlapped with the partition layer.

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19. (New) A light-emitting device comprising:

a conductive film formed over a first insulating film;

a second insulating film formed over the first insulating film;

an electrode of a light-emitting element formed over the second insulating film;

a partition layer covering an edge of the electrode of the light-emitting element; and

a color filter formed over the electrode of the light-emitting element,

wherein the electrode of the light-emitting element is electrically connected to the conductive film in the contact hole,

wherein the electrode of the light-emitting element is formed so that at least a portion of the electrode of the light-emitting element is overlapped with the conductive film,

wherein an opening of the partition layer is provided in an overlap portion of the electrode of the light-emitting element and the conductive film, and

wherein the color filter is overlapped with the overlap portion of the electrode of the light-emitting element and the conductive film.

20. (New) The light-emitting device according to claim 1, wherein the light-emitting device is an active matrix display device.

21. (New) The light-emitting device according to claim 13, wherein the light-emitting device is an active matrix display device.

22. (New) The light-emitting device according to claim 18, wherein the light-emitting device is an active matrix display device.

23. (New) The light-emitting device according to claim 19, wherein the light-emitting device is an active matrix display device.

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